

Welcome to **E-XFL.COM**

Understanding <u>Embedded - FPGAs (Field Programmable Gate Array)</u>

Embedded - FPGAs, or Field Programmable Gate Arrays, are advanced integrated circuits that offer unparalleled flexibility and performance for digital systems. Unlike traditional fixed-function logic devices, FPGAs can be programmed and reprogrammed to execute a wide array of logical operations, enabling customized functionality tailored to specific applications. This reprogrammability allows developers to iterate designs quickly and implement complex functions without the need for custom hardware.

Applications of Embedded - FPGAs

The versatility of Embedded - FPGAs makes them indispensable in numerous fields. In telecommunications.

Details	
Product Status	Obsolete
Number of LABs/CLBs	2566
Number of Logic Elements/Cells	25660
Total RAM Bits	1944576
Number of I/O	597
Number of Gates	-
Voltage - Supply	1.425V ~ 1.575V
Mounting Type	Surface Mount
Operating Temperature	0°C ~ 85°C (TJ)
Package / Case	780-BBGA
Supplier Device Package	780-FBGA (29x29)
Purchase URL	https://www.e-xfl.com/product-detail/intel/ep1s25f780c7

Email: info@E-XFL.COM

Address: Room A, 16/F, Full Win Commercial Centre, 573 Nathan Road, Mongkok, Hong Kong

viii Altera Corporation

Table 2–13 shows the number of DSP blocks in each Stratix device.

Table 2–13. DSP Blocks in Stratix Devices Notes (1), (2)										
Device	DSP Blocks	Total 9 × 9 Multipliers	Total 18 × 18 Multipliers	Total 36 × 36 Multipliers						
EP1S10	6	48	24	6						
EP1S20	10	80	40	10						
EP1S25	10	80	40	10						
EP1S30	12	96	48	12						
EP1S40	14	112	56	14						
EP1S60	18	144	72	18						
EP1S80	22	176	88	22						

Notes to Table 2–13:

- (1) Each device has either the number of 9×9 -, 18×18 -, or 36×36 -bit multipliers shown. The total number of multipliers for each device is not the sum of all the multipliers.
- (2) The number of supported multiply functions shown is based on signed/signed or unsigned/unsigned implementations.

DSP block multipliers can optionally feed an adder/subtractor or accumulator within the block depending on the configuration. This makes routing to LEs easier, saves LE routing resources, and increases performance, because all connections and blocks are within the DSP block. Additionally, the DSP block input registers can efficiently implement shift registers for FIR filter applications.

Figure 2–30 shows the top-level diagram of the DSP block configured for 18×18 -bit multiplier mode. Figure 2–31 shows the 9×9 -bit multiplier configuration of the DSP block.

single DSP block can implement two sums or differences from two 18×18 -bit multipliers each or four sums or differences from two 9×9 -bit multipliers each.

You can use the two-multipliers adder mode for complex multiplications, which are written as:

$$(a+jb)\times(c+jd) = [(a\times c) - (b\times d)] + j\times[(a\times d) + (b\times c)]$$

The two-multipliers adder mode allows a single DSP block to calculate the real part $[(a \times c) - (b \times d)]$ using one subtractor and the imaginary part $[(a \times d) + (b \times c)]$ using one adder, for data widths up to 18 bits. Two complex multiplications are possible for data widths up to 9 bits using four adder/subtractor/accumulator blocks. Figure 2–38 shows an 18-bit two-multipliers adder.

Figure 2–38. Two-Multipliers Adder Mode Implementing Complex Multiply

Four-Multipliers Adder Mode

In the four-multipliers adder mode, the DSP block adds the results of two first -stage adder/subtractor blocks. One sum of four 18×18 -bit multipliers or two different sums of two sets of four 9×9 -bit multipliers can be implemented in a single DSP block. The product width for each multiplier must be the same size. The four-multipliers adder mode is useful for FIR filter applications. Figure 2–39 shows the four multipliers adder mode.

The DSP block is divided into eight block units that interface with eight LAB rows on the left and right. Each block unit can be considered half of an 18 × 18-bit multiplier sub-block with 18 inputs and 18 outputs. A local interconnect region is associated with each DSP block. Like an LAB, this interconnect region can be fed with 10 direct link interconnects from the LAB to the left or right of the DSP block in the same row. All row and column routing resources can access the DSP block's local interconnect region. The outputs also work similarly to LAB outputs as well. Nine outputs from the DSP block can drive to the left LAB through direct link interconnects and nine can drive to the right LAB though direct link interconnects. All 18 outputs can drive to all types of row and column routing. Outputs can drive right- or left-column routing. Figures 2–40 and 2–41 show the DSP block interfaces to LAB rows.

DSP Block OA[17..0] MultiTrack MultiTrack Interconnect \ Interconnect A1[17..0] OB[17..0] B1[17..0] OC[17..0] A2[17..0] OD[17..0] B2[17..0] OE[17..0] A3[17..0] OF[17..0] B3[17..0] OG[17..0] A4[17..0] OH[17..0] ►B4[17..0]

Figure 2-40. DSP Block Interconnect Interface

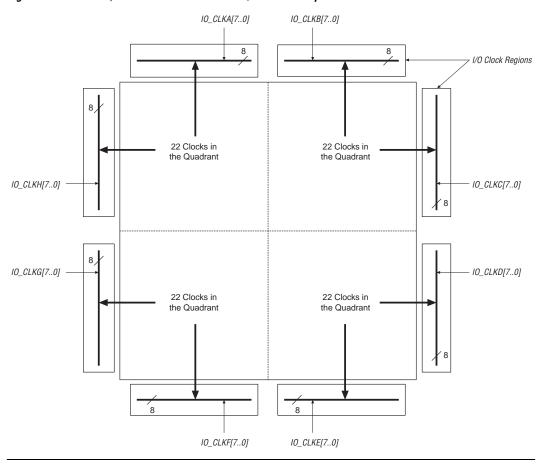
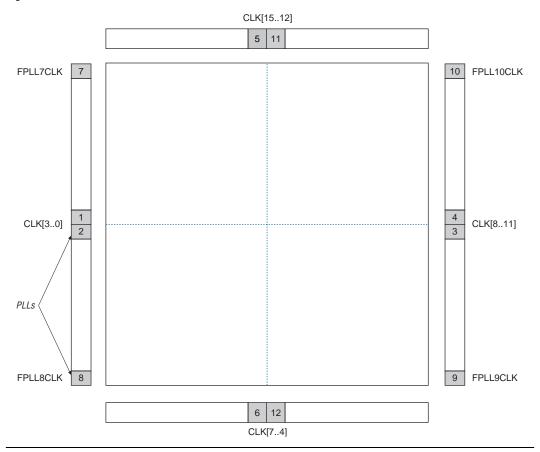


Figure 2-47. EP1S10, EP1S20 & EP1S25 Device I/O Clock Groups

Figure 2–49 shows a top-level diagram of the Stratix device and PLL floorplan.





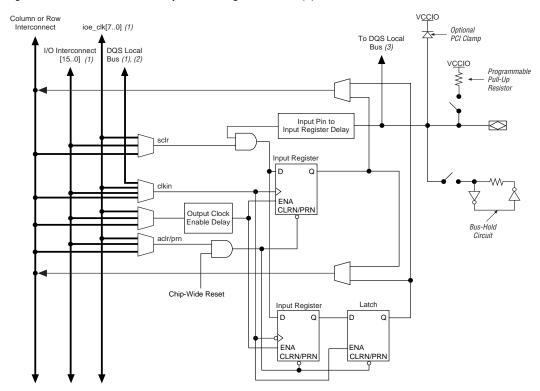


Figure 2–65. Stratix IOE in DDR Input I/O Configuration Note (1)

Notes to Figure 2–65:

- (1) All input signals to the IOE can be inverted at the IOE.
- (2) This signal connection is only allowed on dedicated DQ function pins.
- (3) This signal is for dedicated DQS function pins only.

shift by the same degree amount. For example, all 10 DQS pins on the top of the device can be shifted by 90° and all 10 DQS pins on the bottom of the device can be shifted by 72°. The reference circuits require a maximum of 256 system reference clock cycles to set the correct phase on the DQS delay elements. Figure 2–69 illustrates the phase-shift reference circuit control of each DQS delay shift on the top of the device. This same circuit is duplicated on the bottom of the device.

Input
Reference
Clock
Phase
Comparator
Up/Down
Counter

Delay Chains

Control Signals to DQS Pins

Figure 2-69. Simplified Diagram of the DQS Phase-Shift Circuitry

See the *External Memory Interfaces* chapter in the *Stratix Device Handbook, Volume 2* for more information on external memory interfaces.

Programmable Drive Strength

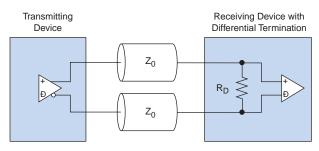
The output buffer for each Stratix device I/O pin has a programmable drive strength control for certain I/O standards. The LVTTL and LVCMOS standard has several levels of drive strength that the user can control. SSTL-3 Class I and II, SSTL-2 Class I and II, HSTL Class I and II, and 3.3-V GTL+ support a minimum setting, the lowest drive strength that guarantees the I_{OH}/I_{OL} of the standard. Using minimum settings provides signal slew rate control to reduce system noise and signal overshoot.



For more information on I/O standards supported by Stratix devices, see the *Selectable I/O Standards in Stratix & Stratix GX Devices* chapter of the *Stratix Device Handbook, Volume 2*.

Stratix devices contain eight I/O banks in addition to the four enhanced PLL external clock out banks, as shown in Figure 2–70. The four I/O banks on the right and left of the device contain circuitry to support high-speed differential I/O for LVDS, LVPECL, 3.3-V PCML, and HyperTransport inputs and outputs. These banks support all I/O standards listed in Table 2–31 except PCI I/O pins or PCI-X 1.0, GTL, SSTL-18 Class II, and HSTL Class II outputs. The top and bottom I/O banks support all single-ended I/O standards. Additionally, Stratix devices support four enhanced PLL external clock output banks, allowing clock output capabilities such as differential support for SSTL and HSTL. Table 2–32 shows I/O standard support for each I/O bank.

Figure 2-71. LVDS Input Differential On-Chip Termination



I/O banks on the left and right side of the device support LVDS receiver (far-end) differential termination.

Table 2–33 shows the Stratix device differential termination support.

Table 2–33. Differential Termination Supported by I/O Banks							
Differential Termination Support I/O Standard Support Top & Bottom Banks (3, 4, 7 & 8) (1, 2, 5 & 6)							
Differential termination (1), (2)	LVDS		✓				

Notes to Table 2-33:

- (1) Clock pin CLK0, CLK2, CLK9, CLK11, and pins FPLL [7..10] CLK do not support differential termination.
- (2) Differential termination is only supported for LVDS because of a 3.3-V $V_{\rm CCIO}$.

Table 2–34 shows the termination support for different pin types.

Table 2–34. Differential Termination Support Across Pin Types						
Pin Type	R _D					
Top and bottom I/O banks (3, 4, 7, and 8)						
DIFFIO_RX[]	✓					
CLK[0,2,9,11],CLK[4-7],CLK[12-15]						
CLK[1,3,8,10]	✓					
FCLK						
FPLL[710]CLK						

The differential on-chip resistance at the receiver input buffer is 118 $\Omega\!\pm\!20$ %.



3. Configuration & Testing

\$51003-1.3

IEEE Std. 1149.1 (JTAG) Boundary-Scan Support

All Stratix® devices provide JTAG BST circuitry that complies with the IEEE Std. 1149.1a-1990 specification. JTAG boundary-scan testing can be performed either before or after, but not during configuration. Stratix devices can also use the JTAG port for configuration together with either the Quartus® II software or hardware using either Jam Files (.jam) or Jam Byte-Code Files (.jbc).

Stratix devices support IOE I/O standard setting reconfiguration through the JTAG BST chain. The JTAG chain can update the I/O standard for all input and output pins any time before or during user mode through the CONFIG_IO instruction. You can use this ability for JTAG testing before configuration when some of the Stratix pins drive or receive from other devices on the board using voltage-referenced standards. Since the Stratix device may not be configured before JTAG testing, the I/O pins may not be configured for appropriate electrical standards for chip-to-chip communication. Programming those I/O standards via JTAG allows you to fully test the I/O connection to other devices.

The enhanced PLL reconfiguration bits are part of the JTAG chain before configuration and after power-up. After device configuration, the PLL reconfiguration bits are not part of the JTAG chain.

The JTAG pins support 1.5-V/1.8-V or 2.5-V/3.3-V I/O standards. The TDO pin voltage is determined by the $V_{\rm CCIO}$ of the bank where it resides. The VCCSEL pin selects whether the JTAG inputs are 1.5-V, 1.8-V, 2.5-V, or 3.3-V compatible.

Stratix devices also use the JTAG port to monitor the logic operation of the device with the SignalTap[®] II embedded logic analyzer. Stratix devices support the JTAG instructions shown in Table 3–1.

The Quartus II software has an Auto Usercode feature where you can choose to use the checksum value of a programming file as the JTAG user code. If selected, the checksum is automatically loaded to the USERCODE register. In the Settings dialog box in the Assignments menu, click **Device & Pin Options**, then **General**, and then turn on the **Auto Usercode** option.

Table 4-10	D. 3.3-V LVDS I/O Specification	ons (Part 2 of 2)				
Symbol	Parameter	Conditions	Minimum	Typical	Maximum	Unit
V _{ICM}	Input common mode voltage (6)	LVDS $0.3 \text{ V} \leq \text{V}_{\text{ID}} \leq 1.0 \text{ V}$ W = 1 through 10	100		1,100	mV
		LVDS $0.3 \text{ V} \leq \text{V}_{\text{ID}} \leq 1.0 \text{ V}$ W = 1 through 10	1,600		1,800	mV
		LVDS 0.2 V ≤V _{ID} ≤1.0 V W = 1	1,100		1,600	mV
		LVDS $0.1 \text{ V} \leq \text{V}_{\text{ID}} \leq 1.0 \text{ V}$ W = 2 through 10	1,100		1,600	mV
V _{OD} (1)	Output differential voltage (single-ended)	R _L = 100 Ω	250	375	550	mV
Δ V _{OD}	Change in V _{OD} between high and low	R _L = 100 Ω			50	mV
V _{OCM}	Output common mode voltage	R _L = 100 Ω	1,125	1,200	1,375	mV
Δ V _{OCM}	Change in V _{OCM} between high and low	R _L = 100 Ω			50	mV
R _L	Receiver differential input discrete resistor (external to Stratix devices)		90	100	110	Ω

Symbol	Parameter	Conditions	Minimum	Typical	Maximum	Unit
V _{CCIO}	Output supply voltage		2.375	2.5	2.625	V
V_{TT}	Termination voltage		V _{REF} - 0.04	V_{REF}	V _{REF} + 0.04	V
V_{REF}	Reference voltage		1.15	1.25	1.35	V
V _{IH(DC)}	High-level DC input voltage		V _{REF} + 0.18		3.0	V
V _{IL(DC)}	Low-level DC input voltage		-0.3		V _{REF} – 0.18	V
V _{IH(AC)}	High-level AC input voltage		V _{REF} + 0.35			V
V _{IL(AC)}	Low-level AC input voltage				V _{REF} - 0.35	٧
V _{OH}	High-level output voltage	$I_{OH} = -8.1 \text{ mA}$ (3)	V _{TT} + 0.57			V
V _{OL}	Low-level output voltage	I _{OL} = 8.1 mA (3)			V _{TT} – 0.57	V

Table 4-21	Table 4–21. SSTL-2 Class II Specifications												
Symbol	Parameter	Conditions	Minimum	Typical	Maximum	Unit							
V _{CCIO}	Output supply voltage		2.375	2.5	2.625	V							
V _{TT}	Termination voltage		V _{REF} – 0.04	V_{REF}	V _{REF} + 0.04	V							
V _{REF}	Reference voltage		1.15	1.25	1.35	V							
V _{IH(DC)}	High-level DC input voltage		V _{REF} + 0.18		V _{CCIO} + 0.3	٧							
V _{IL(DC)}	Low-level DC input voltage		-0.3		V _{REF} – 0.18	V							
V _{IH(AC)}	High-level AC input voltage		V _{REF} + 0.35			V							
V _{IL(AC)}	Low-level AC input voltage				V _{REF} – 0.35	V							
V _{OH}	High-level output voltage	$I_{OH} = -16.4 \text{ mA}$ (3)	V _{TT} + 0.76			V							
V _{OL}	Low-level output voltage	I _{OL} = 16.4 mA (3)			V _{TT} – 0.76	V							

Table 4-22	Table 4–22. SSTL-3 Class I Specifications (Part 1 of 2)												
Symbol	Parameter	Conditions	Minimum	Typical	Maximum	Unit							
V _{CCIO}	Output supply voltage		3.0	3.3	3.6	V							
V _{TT}	Termination voltage		V _{REF} - 0.05	V_{REF}	V _{REF} + 0.05	V							
V _{REF}	Reference voltage		1.3	1.5	1.7	V							
V _{IH(DC)}	High-level DC input voltage		V _{REF} + 0.2		V _{CCIO} + 0.3	V							
V _{IL(DC)}	Low-level DC input voltage		-0.3		V _{REF} – 0.2	V							
V _{IH(AC)}	High-level AC input voltage		V _{REF} + 0.4			V							

Symbol	Parameter
t _{SU}	Input, pipeline, and output register setup time before clock
t _H	Input, pipeline, and output register hold time after clock
t _{CO}	Input, pipeline, and output register clock-to-output delay
t _{INREG2PIPE9}	Input Register to DSP Block pipeline register in 9×9 -bit mode
t _{INREG2PIPE18}	Input Register to DSP Block pipeline register in 18 \times 18-bit mode
t _{PIPE2OUTREG2ADD}	DSP Block Pipeline Register to output register delay in Two-Multipliers Adder mode
t _{PIPE2OUTREG4ADD}	DSP Block Pipeline Register to output register delay in Four-Multipliers Adder mode
t _{PD9}	Combinatorial input to output delay for 9 × 9
t _{PD18}	Combinatorial input to output delay for 18 × 18
t _{PD36}	Combinatorial input to output delay for 36 × 36
t _{CLR}	Minimum clear pulse width
t _{CLKHL}	Register minimum clock high or low time. This is a limit on the min time for the clock on the registers in these blocks. The actual performance is dependent upon the internal point-to-point delays in the blocks and may give slower performance as shown in Table 4–36 on page 4–20 and as reported by the timing analyzer in the Quartus II software.

Table 4-77. L	Table 4–77. EP1S30 External I/O Timing on Row Pins Using Regional Clock Networks										
	-5 Spee	d Grade	-6 Spee	-6 Speed Grade		-7 Speed Grade		-8 Speed Grade			
Parameter	Min	Max	Min	Max	Min	Max	Min	Max	Unit		
t _{INSU}	2.322		2.467		2.828		3.342		ns		
t _{INH}	0.000		0.000		0.000		0.000		ns		
t _{OUTCO}	2.731	5.408	2.731	5.843	2.731	6.360	2.731	7.036	ns		
t _{XZ}	2.758	5.462	2.758	5.899	2.758	6.428	2.758	7.118	ns		
t _{ZX}	2.758	5.462	2.758	5.899	2.758	6.428	2.758	7.118	ns		
t _{INSUPLL}	1.291		1.283		1.469		1.832		ns		
t _{INHPLL}	0.000		0.000		0.000		0.000		ns		
t _{OUTCOPLL}	1.192	2.539	1.192	2.737	1.192	2.786	1.192	2.742	ns		
t _{XZPLL}	1.219	2.539	1.219	2.793	1.219	2.854	1.219	2.824	ns		
t _{ZXPLL}	1.219	2.539	1.219	2.793	1.219	2.854	1.219	2.824	ns		

Table 4-78. I	Table 4–78. EP1S30 External I/O Timing on Row Pins Using Global Clock Networks										
	-5 Spee	d Grade	-6 Spee	-6 Speed Grade		-7 Speed Grade		-8 Speed Grade			
Parameter	Min	Max	Min	Max	Min	Max	Min	Max	Unit		
t _{INSU}	1.995		2.089		2.398		2.830		ns		
t _{INH}	0.000		0.000		0.000		0.000		ns		
t _{OUTCO}	2.917	5.735	2.917	6.221	2.917	6.790	2.917	7.548	ns		
t _{XZ}	2.944	5.789	2.944	6.277	2.944	6.858	2.944	7.630	ns		
t _{ZX}	2.944	5.789	2.944	6.277	2.944	6.858	2.944	7.630	ns		
t _{INSUPLL}	1.337		1.312		1.508		1.902		ns		
t _{INHPLL}	0.000		0.000		0.000		0.000		ns		
t _{OUTCOPLL}	1.164	2.493	1.164	2.708	1.164	2.747	1.164	2.672	ns		
t _{XZPLL}	1.191	2.547	1.191	2.764	1.191	2.815	1.191	2.754	ns		
t _{ZXPLL}	1.191	2.547	1.191	2.764	1.191	2.815	1.191	2.754	ns		

Tables 4–79 through 4–84 show the external timing parameters on column and row pins for EP1S40 devices.

Table 4-79. I	Table 4–79. EP1S40 External I/O Timing on Column Pins Using Fast Regional Clock Networks												
	-5 Spee	d Grade	-6 Speed Grade		-7 Speed Grade		-8 Speed Grade						
Parameter	Min	Max	Min	Max	Min	Max	Min	Max	Unit				
t _{INSU}	2.696		2.907		3.290		2.899		ns				
t _{INH}	0.000		0.000		0.000		0.000		ns				
t _{OUTCO}	2.506	5.015	2.506	5.348	2.506	5.809	2.698	7.286	ns				
t _{XZ}	2.446	4.889	2.446	5.216	2.446	5.685	2.638	7.171	ns				
t _{ZX}	2.446	4.889	2.446	5.216	2.446	5.685	2.638	7.171	ns				

Table 4–80. EP1S40 External I/O Timing on Column Pins Using Regional Clock Networks									
Parameter	-5 Spee	d Grade	rade -6 Speed Grade		-7 Speed Grade		-8 Speed Grade		11!4
Parameter	Min	Max	Min	Max	Min	Max	Min Max Unit		
t _{INSU}	2.413		2.581		2.914		2.938		ns
t _{INH}	0.000		0.000		0.000		0.000		ns
t _{outco}	2.668	5.254	2.668	5.628	2.668	6.132	2.869	7.307	ns
t _{XZ}	2.608	5.128	2.608	5.496	2.608	6.008	2.809	7.192	ns
t _{ZX}	2.608	5.128	2.608	5.496	2.608	6.008	2.809	7.192	ns
t _{INSUPLL}	1.385		1.376		1.609		1.837		ns
t _{INHPLL}	0.000		0.000		0.000		0.000		ns
t _{OUTCOPLL}	1.117	2.382	1.117	2.552	1.117	2.504	1.117	2.542	ns
t _{XZPLL}	1.057	2.256	1,057	2.420	1.057	2.380	1.057	2.427	ns
t _{ZXPLL}	1.057	2.256	1,057	2.420	1.057	2.380	1.057	2.427	ns

Davamatav	-5 Speed Grade -6 Spee		ed Grade -7 Speed		d Grade	-8 Speed Grade			
Parameter	Min	Max	Min	Max	Min	Max	Min	Max	Unit
t _{INSU}	0.884		0.976		1.118		NA		ns
t _{INH}	0.000		0.000		0.000		NA		ns
t _{outco}	3.267	6.274	3.267	6.721	3.267	7.415	NA	NA	ns
t _{XZ}	3.207	6.148	3.207	6.589	3.207	7.291	NA	NA	ns
t _{ZX}	3.207	6.148	3.207	6.589	3.207	7.291	NA	NA	ns
t _{INSUPLL}	0.506		0.656		0.838		NA		ns
t _{INHPLL}	0.000		0.000		0.000		NA		ns
t _{OUTCOPLL}	1.635	2.805	1.635	2.809	1.635	2.828	NA	NA	ns
t _{XZPLL}	1.575	2.679	1.575	2.677	1.575	2.704	NA	NA	ns
t _{ZXPLL}	1.575	2.679	1.575	2.677	1.575	2.704	NA	NA	ns

Table 4–94. l	Table 4–94. EP1880 External I/O Timing on Row Pins Using Fast Regional Clock Networks Note (1)										
Parameter	-5 Speed Grade		-5 Speed Grade		Speed Grade -6 Speed Grade		-7 Speed Grade		-8 Speed Grade		Unit
	Min	Max	Min	Max	Min	Max	Min	Max			
t _{INSU}	2.792		2.993		3.386		NA		ns		
t _{INH}	0.000		0.000		0.000		NA		ns		
t _{OUTCO}	2.619	5.235	2.619	5.609	2.619	6.086	NA	NA	ns		
t _{XZ}	2.646	5.289	2.646	5.665	2.646	6.154	NA	NA	ns		
t _{ZX}	2.646	5.289	2.646	5.665	2.646	6.154	NA	NA	ns		

Table 4–114. Stratix Maximum Input Clock Rate for CLK[7..4] & CLK[15..12] Pins in Flip-Chip Packages (Part 2 of 2)

I/O Standard	-5 Speed Grade	-6 Speed Grade	-7 Speed Grade	-8 Speed Grade	Unit
LVDS (1)	645	645	622	622	MHz
HyperTransport technology (1)	500	500	450	450	MHz

Table 4–115. Stratix Maximum Input Clock Rate for CLK[0, 2, 9, 11] Pins & FPLL[10..7]CLK Pins in Flip-Chip Packages

I/O Standard	-5 Speed Grade	-6 Speed Grade	-7 Speed Grade	-8 Speed Grade	Unit
LVTTL	422	422	390	390	MHz
2.5 V	422	422	390	390	MHz
1.8 V	422	422	390	390	MHz
1.5 V	422	422	390	390	MHz
LVCMOS	422	422	390	390	MHz
GTL+	300	250	200	200	MHz
SSTL-3 Class I	400	350	300	300	MHz
SSTL-3 Class II	400	350	300	300	MHz
SSTL-2 Class I	400	350	300	300	MHz
SSTL-2 Class II	400	350	300	300	MHz
SSTL-18 Class I	400	350	300	300	MHz
SSTL-18 Class II	400	350	300	300	MHz
1.5-V HSTL Class I	400	350	300	300	MHz
1.8-V HSTL Class I	400	350	300	300	MHz
CTT	300	250	200	200	MHz
Differential 1.5-V HSTL C1	400	350	300	300	MHz
LVPECL (1)	717	717	640	640	MHz
PCML (1)	400	375	350	350	MHz
LVDS (1)	717	717	640	640	MHz
HyperTransport technology (1)	717	717	640	640	MHz

Table 4–129. Enhanced PLL Specifications for -7 Speed Grade (Part 2 of 2)							
Symbol	Parameter	Min	Тур	Max	Unit		
t _{OUTDUTY}	Duty cycle for external clock output (when set to 50%)	45		55	%		
t _{JITTER}	Period jitter for external clock output (6)			±100 ps for >200-MHz outclk ±20 mUI for <200-MHz outclk	ps or mUI		
t _{CONFIG5,6}	Time required to reconfigure the scan chains for PLLs 5 and 6			289/f _{SCANCLK}			
t _{CONFIG11,12}	Time required to reconfigure the scan chains for PLLs 11 and 12			193/f _{SCANCLK}			
t _{SCANCLK}	scanclk frequency (5)			22	MHz		
t _{DLOCK}	Time required to lock dynamically (after switchover or reconfiguring any non-post-scale counters/delays) (7) (11)	(9)		100	μs		
t _{LOCK}	Time required to lock from end of device configuration (11)	10		400	μs		
f _{VCO}	PLL internal VCO operating range	300		600 (8)	MHz		
t _{LSKEW}	Clock skew between two external clock outputs driven by the same counter		±50		ps		
t _{SKEW}	Clock skew between two external clock outputs driven by the different counters with the same settings		±75		ps		
f _{SS}	Spread spectrum modulation frequency	30		150	kHz		
% spread	Percentage spread for spread spectrum frequency (10)	0.5		0.6	%		
t _{ARESET}	Minimum pulse width on areset signal	10			ns		

Table 4–130. Enhanced PLL Specifications for -8 Speed Grade (Part 1 of 3)					
Symbol	Parameter	Min	Тур	Max	Unit
f _{IN}	Input clock frequency	3 (1), (2)		480	MHz
f _{INPFD}	Input frequency to PFD	3		420	MHz
f _{INDUTY}	Input clock duty cycle	40		60	%
f _{EINDUTY}	External feedback clock input duty cycle	40		60	%
t _{INJITTER}	Input clock period jitter			±200 (3)	ps

Mode 2–36	Port I/O Standards 2–102
Row & Column Interface Unit	I/O Standards Supported for Enhanced PLL
Signals 2–43	Pins 2–94
Parity Bit Support 2–24	Lock Detect & Programmable Gated
Shift Register	Locked 2–98
Memory Configuration 2–26	PLL Locations 2–84
Support 2–25	Programmable Bandwidth 2–91
Simple Dual-Port & Single-Port Memory	Programmable Delay Chain 2-111
Configurations 2–23	Programmable Duty Cycle 2–98
Stratix IOE in DDR Input I/O	Reconfiguration 2–90
Configuration 2–112	
Stratix IOE in DDR Output I/O	Т
Configuration 2–114	ı
TriMatrix Memory 2–21	Testing
True Dual-Port Memory	Temperature Sensing Diode 3–13
Configuration 2–22	Electrical Characteristics 3–14
	External 3–14
0	Temperature vs. Temperature-Sensing Diode
	Voltage 3–15
Ordering Information 5–1	Timing
Device Pin-Outs 5–1	DSP
Packaging Ordering Information 5–2	Block Internal Timing
Reference & Ordering Information 5–1	Microparameter
Output Registers 2–64	Descriptions 4–23
Output Selection Multiplexer 2–64	Microparameters 4–29
	Dual-Port RAM Timing Microparameter
P	Waveform 4–27
P. 1	External Timing in Stratix Devices 4–33
Packaging	High-Speed I/O Timing 4–87
BGA Package Sizes 1–4	High-Speed Timing Specifications & Terminology 4–87
Device Speed Grades 1–5	Internal Parameters 4–22
FineLine BGA Package Sizes 1–5	IOE Internal Timing Microparameter
PCI-X 1.0 Specifications 4–10	Descriptions 4–22
Phase Shifting 2–103 PLL	LE Internal Timing Microparameters 4–28
Advanced Clear & Enable Control 2–98	Logic Elements Internal Timing Microparam-
Dynamically Programmable Counters & De-	eter Descriptions 4–22
lays in Stratix Device Enhanced	Model 4–19
PLLs 2–91	PLL Timing 4–94
Enhanced	Preliminary & Final 4–19
Fast PLLs 2–81	Stratix Device Timing Model Status 4–19
Fast PLL 2–100	Stratix JTAG
Channel Layout EP1S10, EP1S20 or	Timing Parameters & Values 3–4
EP1S25 Devices 2–138	TriMatrix Memory
Channel Layout EP1S30 to EP1S80	TriMatrix Memory Features 2–21
Devices 2–139	•

Index-6 Altera Corporation